SCLS194C - FEBRUARY 1993 - REVISED APRIL 1996

- EPIC<sup>™</sup> (Enhanced-Performance Implanted CMOS) 2-µ Process
- Typical V<sub>OLP</sub> (Output Ground Bounce)
  < 0.8 V at V<sub>CC</sub>, T<sub>A</sub> = 25°C
- Typical V<sub>OHV</sub> (Output V<sub>OH</sub> Undershoot)
  2 V at V<sub>CC</sub>, T<sub>A</sub> = 25°C
- ESD Protection Exceeds 2000 V Per MIL-STD-883C, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Latch-Up Performance Exceeds 250 mA Per JEDEC Standard JESD-17
- Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), Thin Shrink Small-Outline (PW), Ceramic Flat (W) Packages, Chip Carriers (FK), and (J) 300-mil DIPs

### description

These octal buffers/line drivers are designed for 2.7-V to 5.5-V V<sub>CC</sub> operation.

The 'LV244 are designed specifically to improve both the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

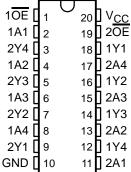
The 'LV244 are organized as two 4-bit line drivers with separate output-enable  $(\overline{OE})$  inputs. When

 $\overline{\text{OE}}$  is low, the device passes data from the A inputs to the Y outputs. When  $\overline{\text{OE}}$  is high, the outputs are in the high-impedance state.

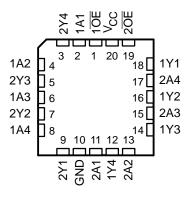
The SN74LV244 is available in TI's shrink small-outline package (DB), which provides the same I/O pin count and functionality of standard small-outline packages in less than half the printed-circuit-board area.

The SN54LV244 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74LV244 is characterized for operation from –40°C to 85°C.

# SN54LV244 . . . J OR W PACKAGE SN74LV244 . . . DB, DW, OR PW PACKAGE (TOP VIEW)



SN54LV244 . . . FK PACKAGE (TOP VIEW)



# FUNCTION TABLE (each buffer)

_		•	
	INP	JTS	OUTPUT
	OE	Α	Y
Γ	L	Н	Н
ı	L	L	L
ı	Н	X	Z

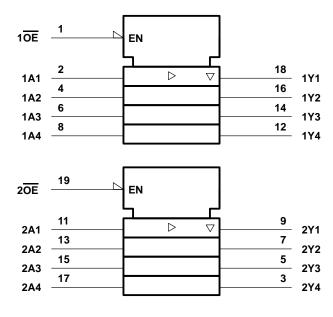


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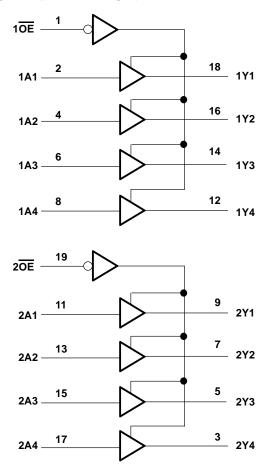
### logic symbol<sup>†</sup>



<sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Pin numbers shown are for DB, DW, J, PW, and W packages.

### logic diagram (positive logic)



## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V <sub>CC</sub> –0.5 V	to 7 V
Input voltage range, V <sub>I</sub> (see Note 1)	+ 0.5 V
Output voltage range, V <sub>O</sub> (see Notes 1 and 2)	+ 0.5 V
Input clamp current, $I_{IK}$ ( $V_I < 0$ or $V_I > V_{CC}$ ) $\pm 1$	20 mA
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0 or V <sub>O</sub> > V <sub>CC</sub> ) ±	50 mA
Continuous output current, $I_O$ ( $V_O = 0$ to $V_{CC}$ ) $\pm$	35 mA
Continuous current through V <sub>CC</sub> or GND ±	70 mA
Maximum power dissipation at T <sub>A</sub> = 55°C (in still air) (see Note 3): DB package	0.6 W
DW package	1.6 W
PW package	0.7 W
Storage temperature range, T <sub>stg</sub> –65°C to	150°C

<sup>\$</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
  - 2. This value is limited to 7 V maximum.
  - 3. The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils.



### recommended operating conditions (see Note 4)

			SN54L	_V244	SN74LV244		UNIT
			MIN	MAX	MIN	MAX	UNII
Vсс	Supply voltage		2.7	5.5	2.7	5.5	V
\/	High-level input voltage	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2		2		V
VIH	nigri-ievei iriput voitage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	3.15		3.15		\ \ \
VIL	Low-level input voltage	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		0.8		0.8	V
	Low-level iliput voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		1.65		1.65	
VI	Input voltage		0	Vcc	0	VCC	V
۷o	Output voltage		0,	VCC	0	VCC	V
	Ligh lovel output output	V <sub>CC</sub> = 2.7 V to 3.6 V	20	-8		-8	A
ЮН	High-level output current	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	130	-16		-16	mA
	Low level output ourrent	V <sub>CC</sub> = 2.7 V to 3.6 V	Q .	8		8	mA
OL	Low-level output current $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$			16		16	IIIA
Δt/Δν	Input transition rise or fall rate	-	0	100	0	100	ns/V
T <sub>A</sub>	Operating free-air temperature		-55	125	-40	85	°C

NOTE 4: Unused inputs must be held high or low to prevent them from floating.

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEGT CONDITIONS	, <sub>+</sub>	SN54LV244			SN74LV244				
PARAMETER	TEST CONDITIONS	v <sub>cc</sub> †	MIN	TYP	MAX	MIN	TYP	MAX	UNIT	
	I <sub>OH</sub> = -100 μA	MIN to MAX	V <sub>CC</sub> – C	).2		V <sub>CC</sub> - 0	.2			
Vон	$I_{OH} = -8 \text{ mA}$	3 V	2.4			2.4			V	
	$I_{OH} = -16 \text{ mA}$	4.5 V	3.6			3.6				
	I <sub>OL</sub> = 100 μA	MIN to MAX			0.2			0.2		
$V_{OL}$	$I_{OL} = 8 \text{ mA}$	3 V			0.4			0.4	V	
	I <sub>OL</sub> = 16 mA	4.5 V			₹0.55			0.55		
1.	V V or CND	3.6 V		Š	±1			±1	μА	
ΙΙ	$V_I = V_{CC}$ or GND	5.5 V		BA	±1			±1		
1	Vo Vocas CND	3.6 V		7	±5			±5		
loz	$V_O = V_{CC}$ or GND	5.5 V	· c	5	±5			±5	μΑ	
1	V - V CND	3.6 V	Õ	/	20			20		
ICC	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V	Q		20			20	μΑ	
ΔICC	One input at V <sub>CC</sub> – 0.6 V, Other inputs at V <sub>CC</sub> or GND	3 V to 3.6 V			500			500	μА	
	V V OND	3.3 V		3			3			
C <sub>i</sub>	$V_I = V_{CC}$ or GND	5 V		3			3		pF	
_		3.3 V		8			8		_	
Co	VO = VCC or GND	5 V		8			8		pF	

<sup>†</sup> For conditions shown as MIN or MAX, use the appropriate values under recommended operating conditions.

## SN54LV244, SN74LV244 OCTAL BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

SCLS194C - FEBRUARY 1993 - REVISED APRIL 1996

# switching characteristics over recommended operating free-air temperature range, $C_L$ = 50 pF (unless otherwise noted) (see Figure 1)

		TO (OUTPUT)	SN54LV244								
PARAMETER	FROM (INPUT)		$V_{CC}$ = 5 V $\pm$ 0.5 V		$V_{CC}$ = 3.3 V $\pm$ 0.3 V			V <sub>CC</sub> = 2.7 V		UNIT	
			MIN	TYP	MAX	- MIN	TYP	MAX	MIN	MAX	
t <sub>pd</sub>	Α	Υ		7	12	W	9	14	W	17	ns
t <sub>en</sub>	ŌĒ	Υ		10	19	M	13	23	111	29	ns
<sup>t</sup> dis	ŌĒ	Υ		10	20		13	21		24	ns

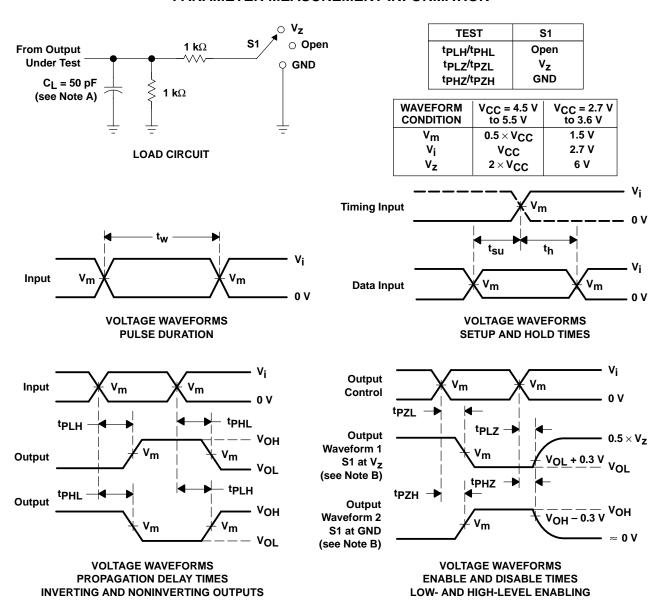
# switching characteristics over recommended operating free-air temperature range, $C_L$ = 50 pF (unless otherwise noted) (see Figure 1)

			SN74LV244								
PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC}$ = 5 V $\pm$ 0.5 V		$V_{CC}$ = 3.3 V $\pm$ 0.3 V			V <sub>CC</sub> = 2.7 V		UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	MAX	
t <sub>pd</sub>	А	Y		7	12		9	14		17	ns
t <sub>en</sub>	ŌĒ	Υ		10	19		13	23		29	ns
<sup>t</sup> dis	ŌĒ	Y		10	20		13	21		24	ns

# operating characteristics, $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	VCC	TYP	UNIT	
C <sub>pd</sub>		Outputs enabled		3.3 V	40	
	Power dissipation capacitance per buffer/driver	Outputs disabled	$C_1 = 50 \text{ pF},  f = 10 \text{ MHz}$	3.5 V	4	pF
		Outputs enabled	С <u> — 30 рг</u> ,  — 10 імпіг	5 V	73	рі
		Outputs disabled		5 V	4	

#### PARAMETER MEASUREMENT INFORMATION



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $t_f \leq$  2.5 ns,  $t_f \leq$  2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLz and tpHz are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tplH and tpHL are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms



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